

## Applications

- Crystal-driven clock source

## General Description

The Vaishali VT73127 is a single-chip, low-jitter Voltage-Controlled-Crystal-Oscillator. The device accepts a 27 MHz, 20 pF crystal input, and produces a low jitter output at the same frequency. The output is enabled when OE is logic HIGH and goes into high impedance state when OE is logic LOW. A 0 to 3.0V control signal is used to fine tune the output clock frequency in the  $\pm 100$ ppm range.

## Features

- 3.3V operating voltage
- Uses inexpensive pullable crystals
- 12mA drive capability at TTL levels
- On-chip oscillator with 200 ppm pull range ( $\pm 100$  ppm)
- Active High output enable
- Die only

**Figure 1. Functional Block Diagram**

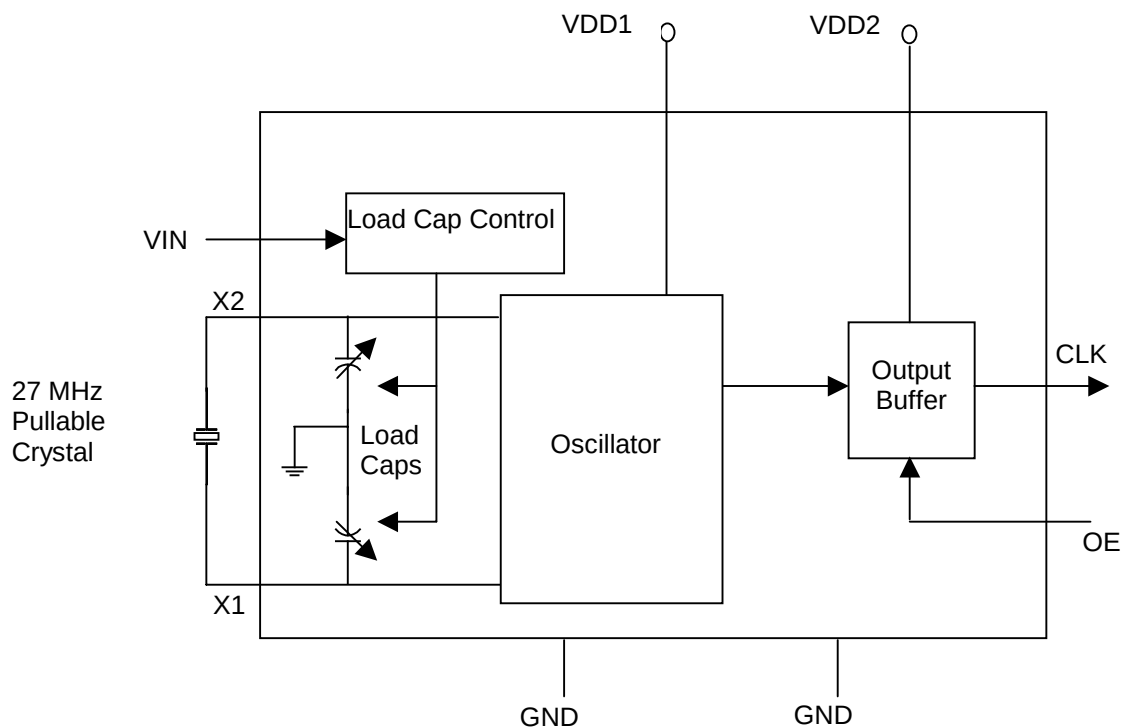


Figure 2. Pad Configuration

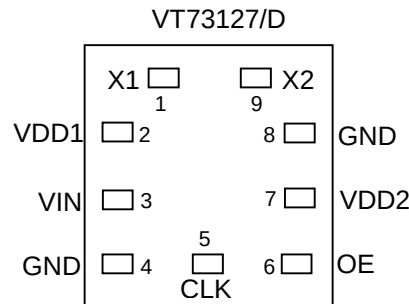


Table 1. Pad Description

| Name | Pad | Type | Description                                                                      |
|------|-----|------|----------------------------------------------------------------------------------|
| X1   | 1   | Xi   | Crystal connection. Connect to a 27 MHz pullable crystal                         |
| VDD1 | 2   | P    | Core $V_{DD}$ . Connect to 3.3V                                                  |
| VIN  | 3   | I    | Tuning control input. Zero to 3.3V signal controls the frequency of the VCXO.    |
| GND  | 4   | P    | Connect to ground.                                                               |
| CLK  | 5   | O    | Clock output                                                                     |
| OE   | 6   | I    | Active HIGH output enable. When LOW, the output is held in a tri-state condition |
| VDD2 | 7   | P    | Output buffer $V_{DD}$ . Connect to 3.3V                                         |
| GND  | 8   | P    | Connect to ground.                                                               |
| X2   | 9   | Xi   | Crystal connection. Connect to a 27 MHz pullable crystal.                        |

Legend: I = Input  
 O = Output  
 P = Power supply connection  
 Xi = Crystal connections.

Table 2. Absolute Maximum Ratings

| Parameter                | Conditions        | Min  | Typ | Max          | Units |
|--------------------------|-------------------|------|-----|--------------|-------|
| Supply voltage, $V_{DD}$ | Referenced to GND |      |     | 7            | V     |
| Inputs and Clock Outputs | Referenced to GND | -0.5 |     | $V_{DD}+0.5$ | V     |
| Soldering Temperature    | Max of 10 seconds |      |     | 260          | °C    |
| Storage temperature      |                   | -65  |     | 150          | °C    |

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress specifications only and correct functional operation of the device at these or any other conditions above those listed in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Table 3. Operating Conditions

| Parameter                                  | Conditions | Min | Typ | Max | Units |
|--------------------------------------------|------------|-----|-----|-----|-------|
| Operating Voltage, $V_{DD}$                |            | 3.0 | 3.3 | 3.6 | V     |
| Input High Voltage, $V_{IH}$ , X1 pin only |            | 2.5 |     |     | V     |
| Input Low Voltage, $V_{IL}$ , X1 pin only  |            |     |     | 0.4 | V     |
| Operating Temperature                      |            | 0   |     | 70  | °C    |
| Input crystal accuracy                     |            |     |     | ±30 | ppm   |

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|                                |  |   |  |     |   |
|--------------------------------|--|---|--|-----|---|
| VCXO control voltage, $V_{IN}$ |  | 0 |  | 3.3 | V |
|--------------------------------|--|---|--|-----|---|

**Table 4. DC Electrical Characteristics** $T_A = 0^{\circ}\text{C}$  to  $+70^{\circ}\text{C}$ ,  $V_{DD} = 3.0\text{ V}$  to  $3.6\text{ V}$ 

| Parameter                          | Condition               | Min | Typ <sup>(1)</sup> | Max | Units |
|------------------------------------|-------------------------|-----|--------------------|-----|-------|
| Output High Voltage, $V_{OH}$      | $I_{OH} = -12\text{mA}$ | 2.4 |                    |     | V     |
| Output Low Voltage, $V_{OL}$       | $I_{OL} = 12\text{mA}$  |     |                    | 0.4 | V     |
| Operating Supply Current, $I_{DD}$ | No Load                 |     | 25                 |     | mA    |
| Short Circuit Current              | Each output             |     | $\pm 85$           |     | mA    |
| Input Capacitance                  |                         |     | 7                  |     | pF    |

**Note:**1. Typical values are at  $V_{DD} = 3.3\text{V}$  and  $25^{\circ}\text{C}$ **Table 5. AC Electrical Characteristics** $T_A = 0^{\circ}\text{C}$  to  $+70^{\circ}\text{C}$ ,  $V_{DD} = 3.0\text{ V}$  to  $3.6\text{ V}$ 

| Symbol                               | Parameter                                 | Condition                                | Min       | Typ | Max | Units |
|--------------------------------------|-------------------------------------------|------------------------------------------|-----------|-----|-----|-------|
| fosc                                 | Input Crystal Frequency                   |                                          |           | 27  |     | MHz   |
| tr                                   | Output Clock Rise Time                    | 0.8 to 2.0V                              |           |     | 1.5 | ns    |
| tf                                   | Output Clock Fall Time                    | 2.0 to 0.8V                              |           |     | 1.5 | ns    |
| t <sub>PZL</sub><br>t <sub>PZH</sub> | Output Enable Time<br>(OE to CLK)         |                                          |           |     | 6.5 | ns    |
| t <sub>PLZ</sub><br>t <sub>PHZ</sub> | Output Disable Time<br>(OE to CLK)        |                                          |           |     | 6.5 | ns    |
| t <sub>od</sub>                      | Output Clock Duty Cycle                   | At $V_{DD}/2$                            | 40        |     | 60  | %     |
| t <sub>jit</sub> (pk – pk)           | Maximum Absolute Jitter<br>(Peak to Peak) |                                          |           |     | 150 | ps    |
|                                      | Output pullability                        | $0\text{V} \leq V_{IN} \leq 3.3\text{V}$ | $\pm 100$ |     |     | ppm   |

**Note:**1. Typical values are at  $V_{DD} = 3.3\text{V}$  and  $25^{\circ}\text{C}$ **Table 6 Pullable Crystal Specifications**

| Parameter                       | Symbol    | Value              |
|---------------------------------|-----------|--------------------|
| Correlation (Load) Capacitance  | $C_L$     | 20pF               |
| Capacitance Ratio               | $C_0/C_1$ | 240 max            |
| ESR                             |           | 50 $\Omega$ max    |
| Initial Accuracy                |           | $\pm 30\text{ppm}$ |
| Temperature and Aging Stability |           | $\pm 50\text{ppm}$ |

**Ordering Information****VT73127**

| Part Number | Marking | Shipping/Packaging  | No. of Pads | Package | Temperature                                  |
|-------------|---------|---------------------|-------------|---------|----------------------------------------------|
| VT73127/D   |         | Dice in waffle-pack |             |         | $0^{\circ}\text{C}$ to $+70^{\circ}\text{C}$ |
| VT73127/DW  |         | Dice in wafer form  |             |         | $0^{\circ}\text{C}$ to $+70^{\circ}\text{C}$ |